SLVS042D - JANUARY 1991 - REVISED JULY 1999

- Power-On Reset Generator
- Automatic Reset Generation After Voltage Drop
- Precision Input Threshold Voltage . . . 4.55 V ±120 mV
- Low Standby Current . . . 20 μA
- Reset Outputs Defined When V<sub>CC</sub> Exceeds 1 V
- True and Complementary Reset Outputs
- Wide Supply-Voltage Range . . . 1 V to 7 V

# D, P, OR PW PACKAGE (TOP VIEW) NC [ 1 8 ] RESET NC [ 2 7 ] RESET NC [ 3 6 ] NC GND [ 4 5 ] V<sub>CC</sub>

NC - No internal connection

### description

The TL7759 is a supply-voltage supervisor designed for use as a reset controller in microcomputer and microprocessor systems. The supervisor monitors the supply voltage for undervoltage conditions. During power up, when the supply voltage,  $V_{CC}$ , attains a value approaching 1 V, the RESET and  $\overline{RESET}$  outputs become active (high and low, respectively) to prevent undefined operation. If the supply voltage drops below the input threshold voltage level ( $V_{IT-}$ ), the reset outputs go to the reset active state until the supply voltage has returned to its nominal value (see timing diagram).

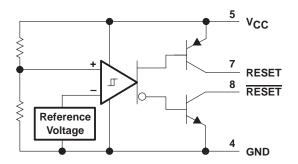
The TL7759C is characterized for operation from 0°C to 70°C.

#### **AVAILABLE OPTIONS**

	PAC			
TA	SMALL OUTLINE (D)	PLASTIC DIP (P)	SHRINK SMALL OUTLINE (PW)	CHIP FORM (Y)
0°C to 70°C	TL7759CD	TL7759CP	TL7759CPW	TL7759Y

The D and PW packages are available taped and reeled. Add the suffix R to the device type (e.g., TL7759CDR). Chip forms are tested at 25°C.

#### functional block diagram





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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub> (see Note 1)	20 V
Off-state output voltage range: RESET voltage	-0.3~V to 20 $V$
RESET voltage	-0.3~V to 20 $V$
Low-level output current, I <sub>OL</sub> (RESET)	30 mA
High-level output current, I <sub>OH</sub> (RESET)	10 mA
Package thermal impedance, θ <sub>JA</sub> (see Notes 2 and 3): D package	97°C/W
P package	127°C/W
PW package	149°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T <sub>stg</sub> –	65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values are with respect to the network ground terminal.
  - 2. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can impact reliability.
  - 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

## recommended operating conditions

	MIN	MAX	UNIT	
Supply voltage, V <sub>CC</sub>	1	7	V	
Output voltage Va (eee Note 4)	Transistor off RESET voltage		15	V
Output voltage, VO (see Note 4)	Transistor off RESET voltage	0		٧
Low-level output current, IOL	RESET		24	mA
High-level output current, IOH	RESET		-8	mA
Operating free-air temperature, T <sub>A</sub>	TL7759C	0	70	°C

NOTE 4: RESET output must not be pulled down below GND potential.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		Т	TL7759C				
				MIN	TYP <sup>‡</sup>	MAX	UNIT		
VOL	Low-level output voltage	RESET	V 42V	I <sub>OL</sub> = 24 mA		0.4	0.8	V	
Vон	High-level output voltage	RESET	V <sub>CC</sub> = 4.3 V	I <sub>OH</sub> = -8 mA	V <sub>CC</sub> -1			V	
VIT- Input threshold voltage (negative-going V <sub>CC</sub> )			$T_A = 25$ °C $T_A = 0$ °C to 70°C		4.43	4.55	4.67	٧	
					4.4		4.7		
	Dower up react veltage		D. 0.0140	T <sub>A</sub> = 25°C		0.8	1	V	
V <sub>res</sub> § Power-up reset voltage			$R_L = 2.2 \text{ k}\Omega$	$T_A = 0$ °C to $70$ °C			1.2	V	
V <sub>hys</sub> ¶ Hysteresis at V <sub>CC</sub> input			T <sub>A</sub> = 25°C		40	50	60	mV	
		$T_A = 0$ °C to $70$ °C		30		70	IIIV		
ЮН	High-level output current	RESET		V <sub>OH</sub> = 15 V			1	μΑ	
lOL	Low-level output current	RESET	V <sub>CC</sub> = 7 V, See Figure 1	V <sub>OL</sub> = 0 V			-1	μΑ	
laa	Cumply augreent		Madaad	V <sub>CC</sub> = 4.3 V		1400	2000		
ICC	Supply current		No load	V <sub>CC</sub> = 5.5 V			μA		

<sup>‡</sup> Typical values are at T<sub>A</sub> = 25°C.

 $<sup>\</sup>P$  This is the difference between positive-going input threshold voltage, V $_{
m IT+}$ , and negative-going input threshold voltage, V $_{
m IT-}$ .



<sup>§</sup> This is the lowest voltage at which  $\overline{\text{RESET}}$  becomes active, V<sub>CC</sub> slew rate  $\leq$  5 V/ $\mu$ s.

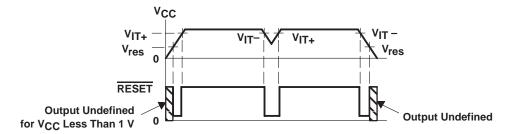
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# electrical characteristics, $T_A = 25^{\circ}C$ (unless otherwise noted)

PARAMETER		TF0T 6	TL7759Y					
		TEST C	MIN	TYP	MAX	UNIT		
VOL	Low-level output voltage	RESET	$V_{CC} = 4.3 \text{ V}, \qquad I_{OL} = 24 \text{ mA}$			0.4		V
V <sub>IT</sub> –	r_ Input threshold voltage (negative-going V <sub>CC</sub> )					4.55		V
v <sub>res</sub> †	V <sub>res</sub> † Power-up reset voltage		R <sub>L</sub> = 2.2 kΩ			0.8		V
V <sub>hys</sub> ‡	V <sub>hys</sub> ‡ Hysteresis at V <sub>CC</sub> input					50		mV
Icc	Supply current		$V_{CC} = 4.3 \text{ V},$	No load		1400		μΑ

<sup>†</sup> This is the lowest voltage at which  $\overline{\text{RESET}}$  becomes active,  $V_{CC}$  slew rate  $\leq 5 \text{ V/}\mu\text{s}$ .

# timing diagram



# switching characteristics at $T_A = 25^{\circ}C$ (unless otherwise noted)

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	TL7759C		UNIT
				TEST CONDITIONS	MIN	MAX	UNII
<sup>t</sup> PLH	Propagation delay time, low-to high-level output	Vcc	RESET	See Figures 2 and 3§		5	μs
tPHL	Propagation delay time, high-to low-level output	Vcc	RESET	See Figures 2 and 4		5	μs
t <sub>r</sub>	Rise time		RESET	See Figures 2 and 4§		1	μs
t <sub>f</sub>	Fall time		RESET	See Figures 2 and 4		1	μs
tw(min)	Minimum pulse duration	Vcc	RESET	See Figures 2 and 4	5		μs

<sup>§</sup> V<sub>CC</sub> slew rate ≤ 5 V/μs

<sup>‡</sup> This is the difference between positive-going input threshold voltage, V<sub>IT+</sub>, and negative-going input threshold voltage, V<sub>IT-</sub>.

### PARAMETER MEASUREMENT INFORMATION

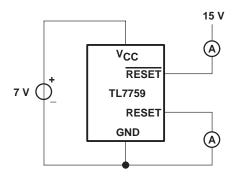
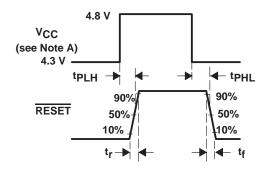
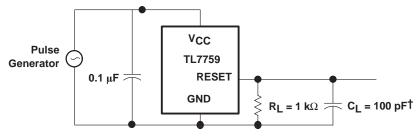


Figure 1. Test Circuit for Output Leakage Current



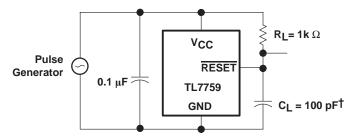
NOTE A:  $V_{CC}$  slew rate  $\leq 5 V/\mu s$ .

Figure 2. Switching Diagram



<sup>†</sup>C<sub>L</sub> Includes jig and probe capacitance.

Figure 3. Test Circuit for RESET Output Switching Characteristics



 $^\dagger C_L$  Includes jig and probe capacitance.

Figure 4. Test Circuit for RESET Output Switching Characteristics



# **APPLICATION INFORMATION**

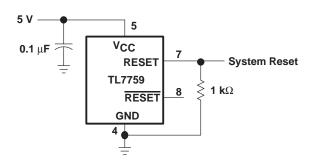


Figure 5. Power-Supply System Reset Generation

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